

**IN THE SPECIFICATION**

1. Please amend the title of the invention as follows:

**FIELD EMISSION DISPLAY INCLUDING MESH GRID  
AND FOCUSING ELECTRODE AND ITS METHOD OF  
MANUFACTURING THE SAME MANUFACTURE**

2. Please amend paragraph [0047] as follows:

[0047] A gate 47 is formed on the insulator 45. The gate 47 has openings corresponding to the holes of the insulator 45 to allow for attraction of electrons emitted from the emitters 46 toward an anode 53. The cathode 55, the emitter and the gate 47 serve as an electron emission assembly. In the illustrated embodiment, it is appreciated that the gate [[46]] 47 is disposed on the upper side of the cathode 55.

3. Please amend paragraph [0050] as follows:

[0050] A mesh grid 50 is formed between the gate 47 and the anode 53 to control electrons emitted from the emitters 46. The mesh grid 50 is disposed on the gate 47. That is, the mesh [[gird]] grid 50 includes lower and upper insulators 49 and 51, which are respectively formed on lower and upper surfaces of the mesh grid 50, and then the mesh grid 50 is disposed on the gate 47. The lower insulator 49 can be replaced with a resistive layer comprising of a resistive material. Further, both the lower and upper insulators 49 and 50 are replaced with the resistive layer. As shown in the drawing, the mesh grid 50 is fixed in such a way that it is bonded to the gate 47 by a frit. The mesh grid

50 serves to block the action of the electric field of the anode 53 on the electron emission of the cathode 55 and to accelerate the emitted electrons. In another embodiment (not shown) in which the cathode is disposed on the upper side of the gate, the mesh grid is disposed upper side of the cathode.